



T12xxH Series 12A TRIACs

Rev.8.0

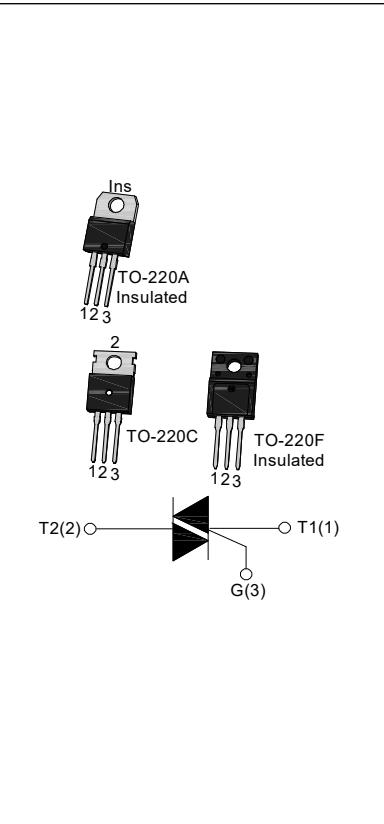
DESCRIPTION:

T12xxH series triacs of high junction temperature with high dv/dt rate with strong resistance to electromagnetic interference provide high ability to withstand the shock loading of large current. They are especially recommended for use on inductive load and high environment temperature condition.

From all three terminals to external heatsink, T12xxH-xxA provides a rated insulation voltage of 2500 V_{RMS}, and T12xxH-xxF provides a rated insulation voltage of 2000 V_{RMS}, complying with UL standards (File ref: E252906). All the packages listed above are RoHS compliant. (2011/65/EU)

MAIN FEATURES

Symbol	Value	Unit
I _{T(RMS)}	12	A
V _{DRM} /V _{RRM}	600/800	V
T _{jmax}	150	°C



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T _{stg}	-40-150	°C
Operating junction temperature range	T _j	-40-150	°C
Repetitive peak off-state voltage(T _j =25°C)	V _{DRM}	600/800	V
Repetitive peak reverse voltage(T _j =25°C)	V _{RRM}	600/800	V
RMS on-state current TO-220A(Ins)/ TO-220F(Ins) (T _c =110°C) TO-220C (T _c =120°C)	I _{T(RMS)}	12	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I _{TSM}	120	A
I ² t value for fusing (tp=10ms)	I ² t	72	A ² s
Critical rate of rise of on-state current (I _G =2×I _{GT})	dI/dt	50	A/μs

Peak gate current	I _{GM}	4	A
Average gate power dissipation	P _{G(AV)}	1	W
Peak gate power	P _{GM}	5	W

ELECTRICAL CHARACTERISTICS (T_j=25°C unless otherwise specified)

Symbol	Test Condition	Quadrant		Value				Unit
				T1210H	T1220H	T1235H	T1250H	
I _{GT}	V _D =12V R _L =33Ω	I - II - III	MAX	10	20	35	50	mA
V _{GT}		I - II - III	MAX	1.3				V
V _{GD}	V _D =V _{DRM} T _j =150°C R _L =3.3KΩ	I - II - III	MIN	0.2				V
I _L	I _G =1.2I _{GT}	I - III	MAX	20	40	50	70	mA
		II		35	55	70	100	
I _H	I _T =100mA		MAX	20	30	45	60	mA
dV/dt	V _D =2/3V _{DRM} R _{GK} =1KΩ T _j =150°C		MIN	200	500	1000	1500	V/μs

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V _{TM}	I _{TM} =17A t _p =380μs	T _j =25°C	1.4	V
V _{TO}	Threshold voltage	T _j =125°C	0.9	V
R _d	Dynamic resistance	T _j =125°C	32	mΩ
I _{DRM}	V _D =V _{DRM} V _R =V _{RRM}	T _j =25°C	5	μA
I _{RRM}		T _j =150°C	2	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th(j-c)}	junction to case(AC)	TO-220A(Ins)/ TO-220F(Ins)	2.5
		TO-220C	
		1.9	°C/W

ORDERING INFORMATION

T	12	20	H	-6	A
Triacs					
<u>I_T(RMS): 12A</u>					
10: I _{GT1-3} ≤ 10mA					
20: I _{GT1-3} ≤ 20mA					
35: I _{GT1-3} ≤ 35mA					
50: I _{GT1-3} ≤ 50mA					
					C: TO-220C A: TO-220A(Ins) F: TO-220F(Ins)
					6: V _{DRM} / V _{RRM} ≥ 600V 8: V _{DRM} / V _{RRM} ≥ 800V
					High junction temperature

MARKING

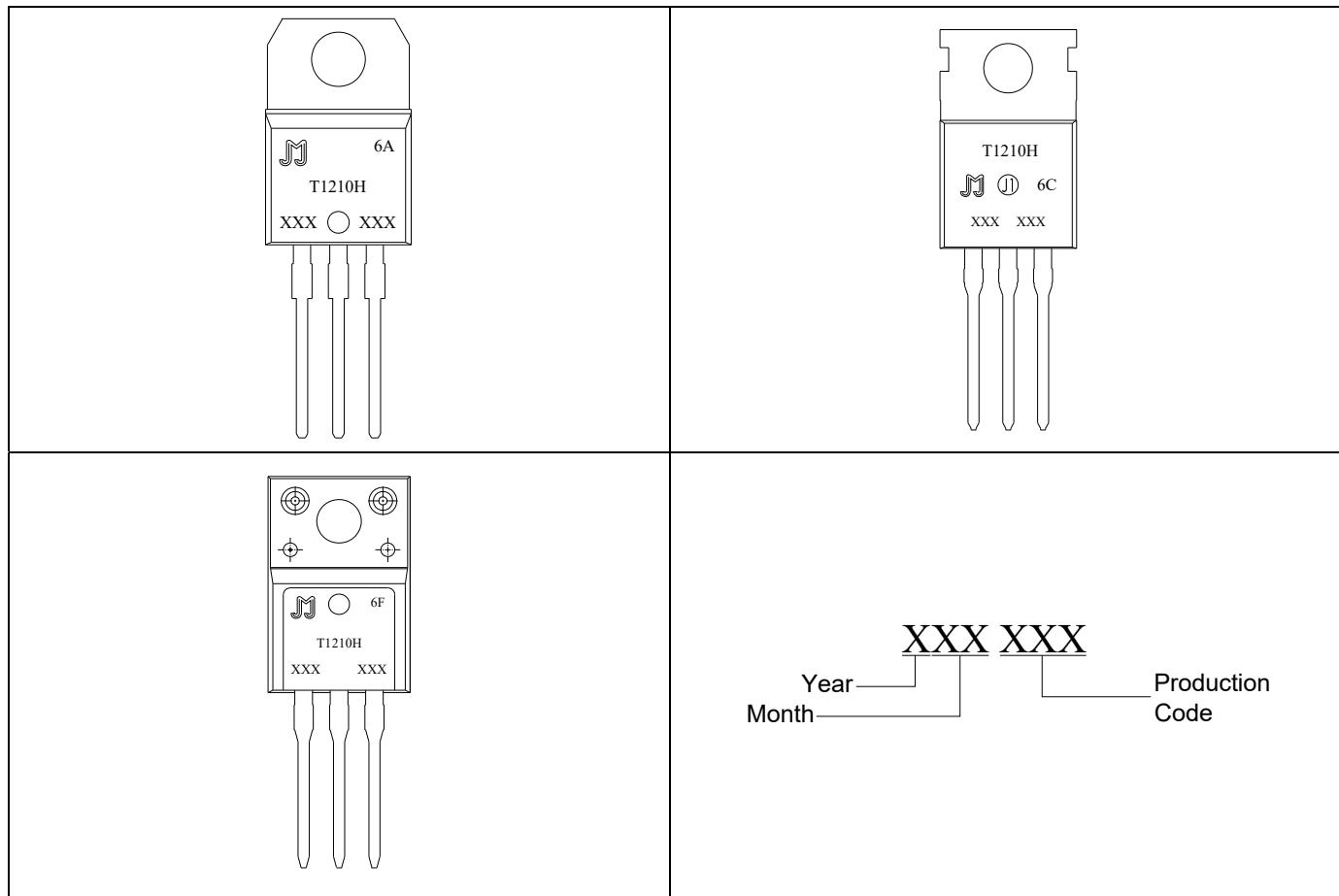


FIG.1: Maximum power dissipation versus RMS on-state current

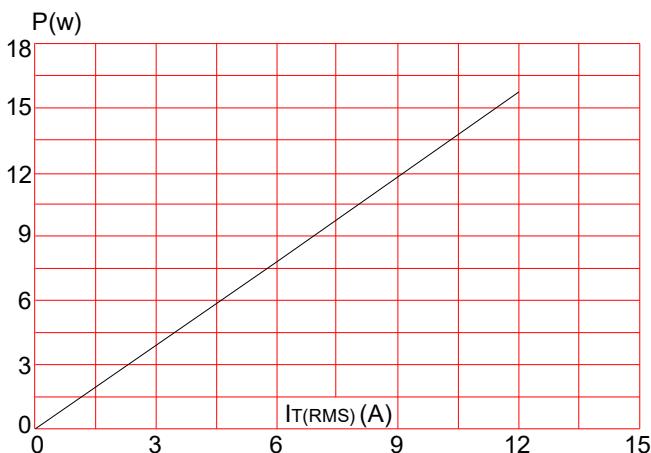


FIG.3: Surge peak on-state current versus number of cycles

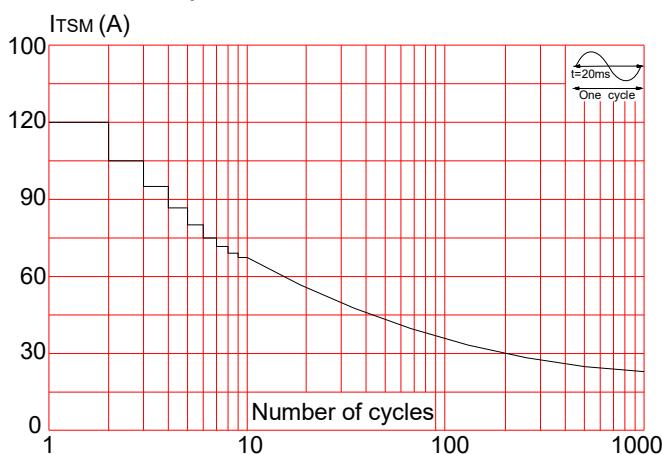


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 20\text{ms}$, and corresponding value of I^2t ($dl/dt < 50\text{A}/\mu\text{s}$)

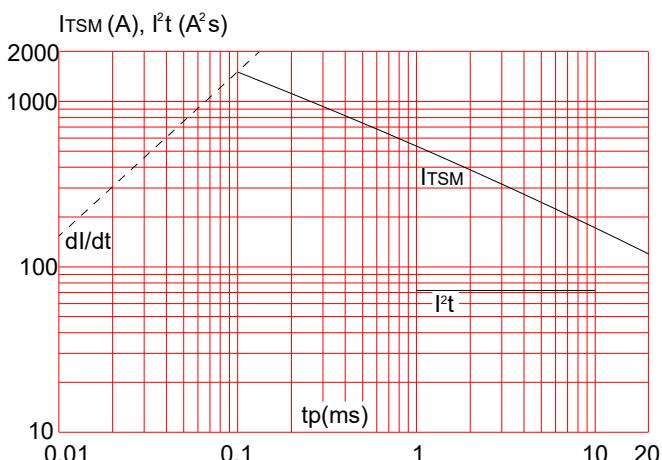


FIG.2: RMS on-state current versus case temperature

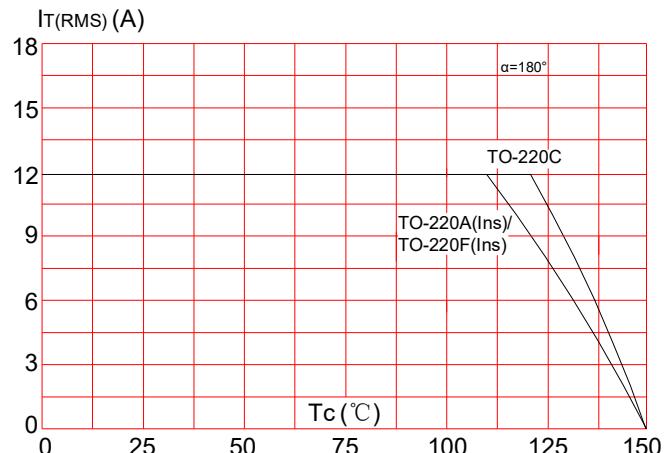


FIG.4: On-state characteristics (maximum values)

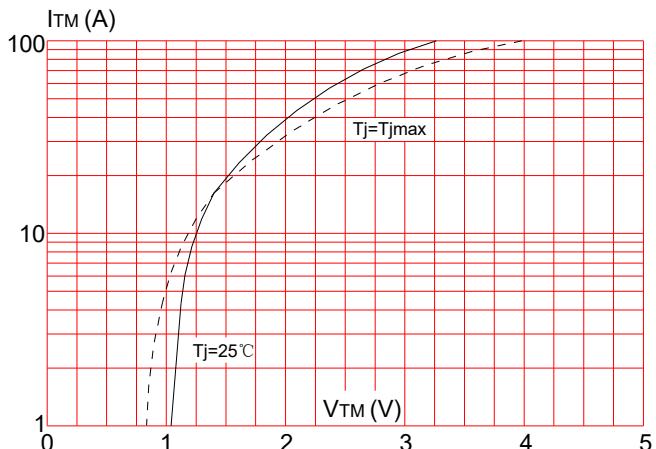
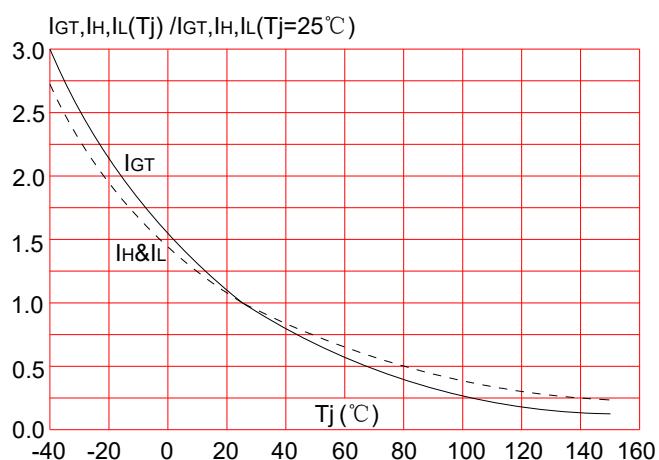


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



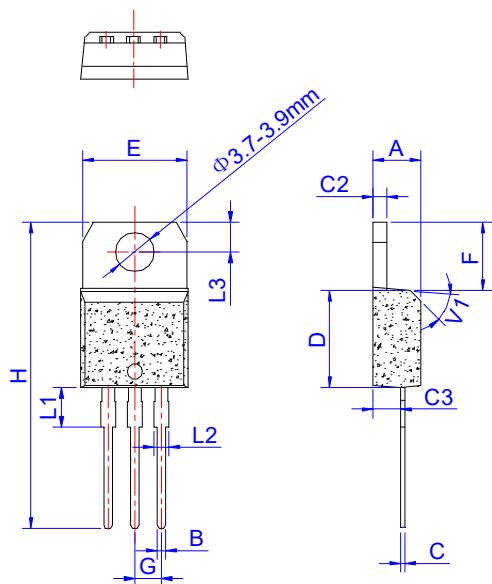
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode		
T1210H-6/8A	600/800	10	TO-220A(Ins)	50	Tube		
T1220H-6/8A		20					
T1235H-6/8A		35					
T1250H-6/8A		50					
T1210H-6/8C		10	TO-220C				
T1220H-6/8C		20					
T1235H-6/8C		35					
T1250H-6/8C		50					
T1210H-6/8F		10	TO-220F(Ins)				
T1220H-6/8F		20					
T1235H-6/8F		35					
T1250H-6/8F		50					

Document Revision History

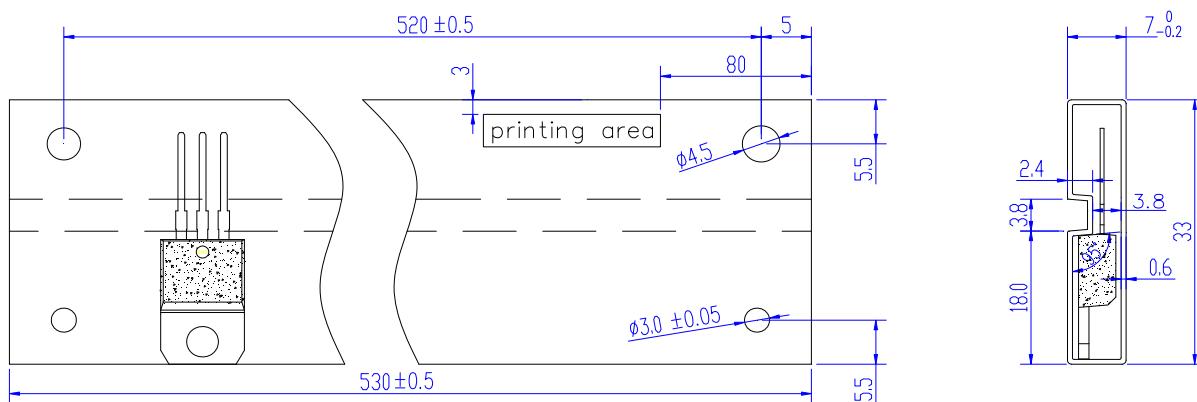
Date	Revision	Changes
Apr 28, 2019	7	Last update
Jul 05, 2022	8	Delete TO-220B package, Add Vto & Rd

PACKAGE MECHANICAL DATA



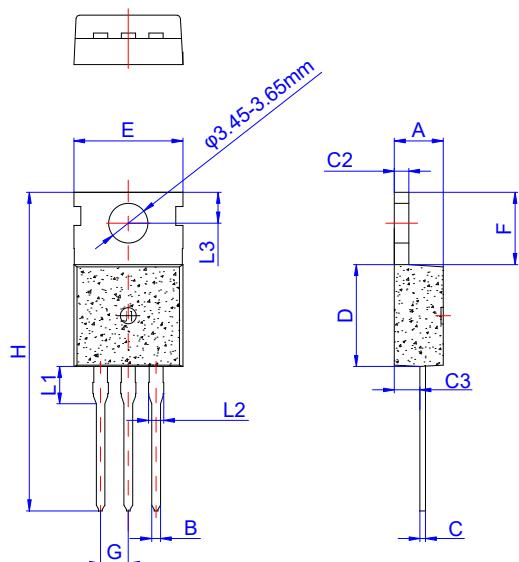
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.25		6.85	0.246		0.270
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.45		4.05	0.136		0.159
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

DELIVERY MODE



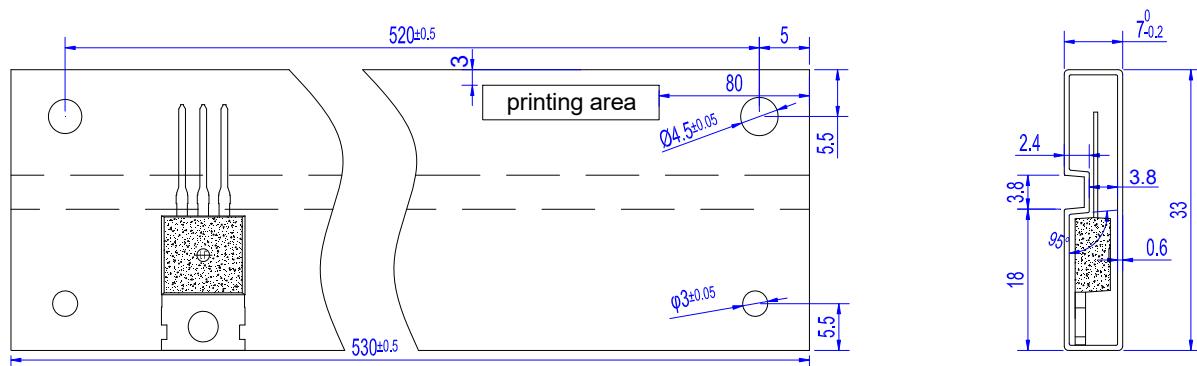
PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220A	TUBE	50	1,000	5,000

PACKAGE MECHANICAL DATA



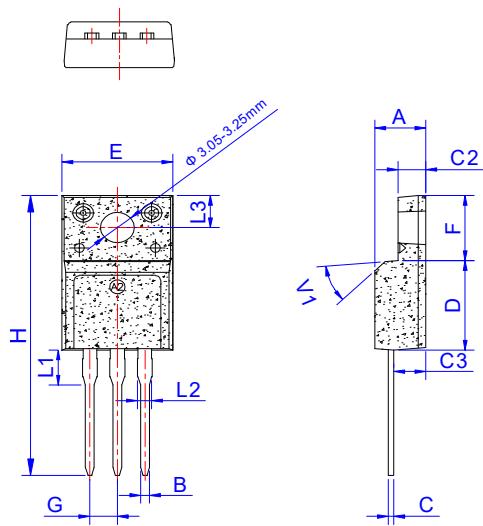
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.25		1.35	0.049		0.053
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.3	0.390		0.406
F	6.30		6.90	0.248		0.272
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	2.70		3.30	0.106		0.130
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116

DELIVERY MODE



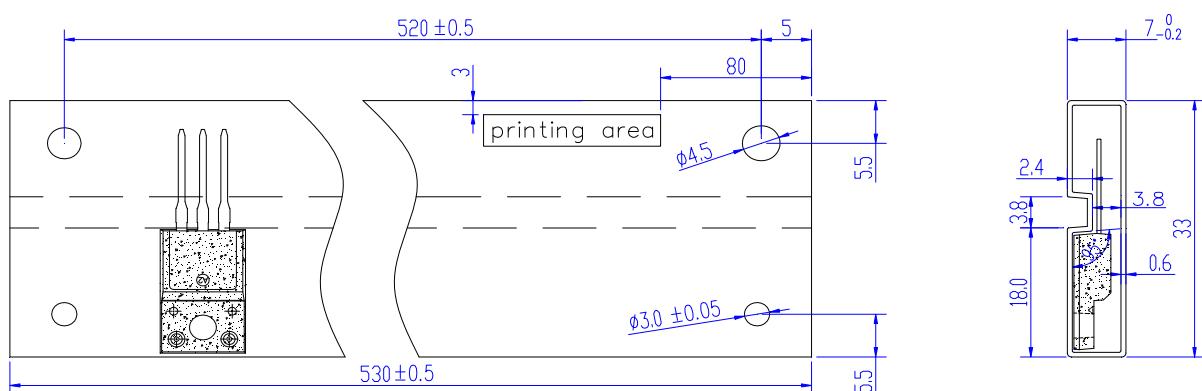
PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220C	TUBE	50	1,000	5,000

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50		4.90	0.177		0.193
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.410
F	6.40		6.80	0.252		0.268
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.20		3.80	0.126		0.150
L2	1.14		1.70	0.045		0.067
L3	3.20		3.60	0.126		0.142
V1		45°			45°	

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220F	TUBE	50	1,000	5,000



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